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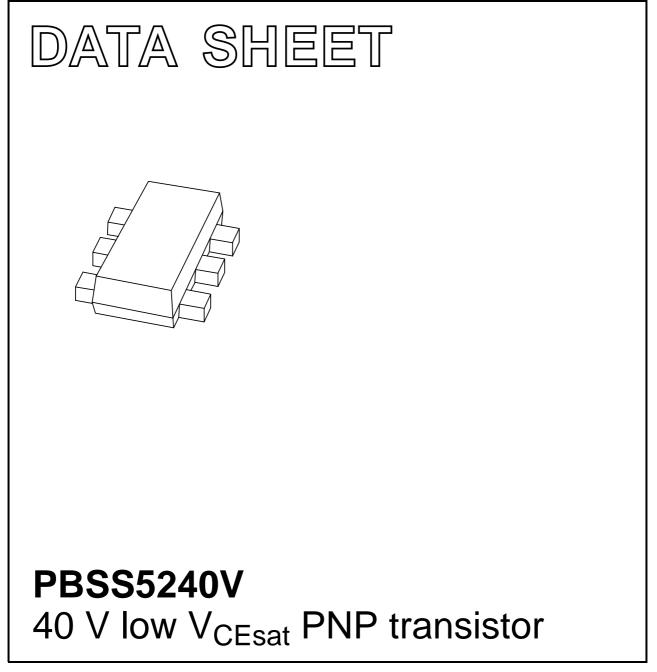
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet

2003 Jan 30



PBSS5240V

FEATURES

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- · High efficiency leading to reduced heat generation
- Reduced printed-circuit board area requirements.

APPLICATIONS

- Power management:
 - DC-DC converter
 - Supply line switching
 - Battery charger
 - LCD back lighting.
- Peripheral driver:
 - Driver in low supply voltage applications (e.g. lamps, LEDs)
 - Inductive load drivers (e.g. relay, buzzers and motors).

DESCRIPTION

PNP transistor providing low V_{CEsat} and high current capability in a SOT666 plastic package. NPN complement: PBSS4240V.

MARKING

TYPE NUMBER	MARKING CODE		
PBSS5240V	52		

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage	-40	V	
I _C	collector current (DC)	-1.8	А	
I _{CRP}	peak collector current -2		А	
R _{CEsat}	equivalent on-resistance	<250	mΩ	

PINNING

PIN	DESCRIPTION	
1	collector	
2	collector	
3	base	
4	emitter	
5	collector	
6	collector	

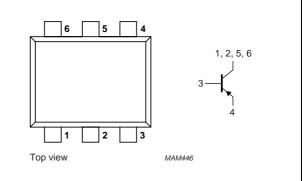


Fig.1 Simplified outline (SOT666) and symbol.

PBSS5240V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-40	V
V _{CEO}	collector-emitter voltage	open base	-	-40	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current (DC)	note 1	-	-1.8	А
I _{CRP}	peak repetitive collector current	note 2	-	-2	А
I _{CM}	peak collector current		-	-3	А
I _B	base current (DC)		-	-300	mA
I _{BM}	peak base current		-	-1	А
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 3	-	300	mW
		$T_{amb} \le 25 \ ^{\circ}C$; note 4	-	500	mW
		$T_{amb} \le 25 \ ^{\circ}C$; note 1	-	900	mW
		$T_{amb} \le 25 \ ^{\circ}C$; notes 2 and 3	-	1.2	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a ceramic circuit board, AI_2O_3 , standard footprint.
- 2. Operated under pulsed conditions: duty cycle δ \leq 20%, pulse width t_p \leq 30 ms.
- 3. Device mounted on a printed-circuit board, single-sided copper, tinplated, standard footprint.
- 4. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	R _{th j-a} thermal resistance from junction to ambient	note 1	410	K/W
		note 2	215	K/W
		note 3	140	K/W
	notes 1 and 4	110	K/W	

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tinplated, standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².
- 3. Device mounted on a ceramic circuit board, Al₂O₃, standard footprint.
- 4. Operated under pulsed conditions: duty cycle $\delta \leq$ 20%, pulse width $t_p \leq$ 30 ms.

Soldering

The only recommended soldering method is reflow soldering.

PBSS5240V

CHARACTERISTICS

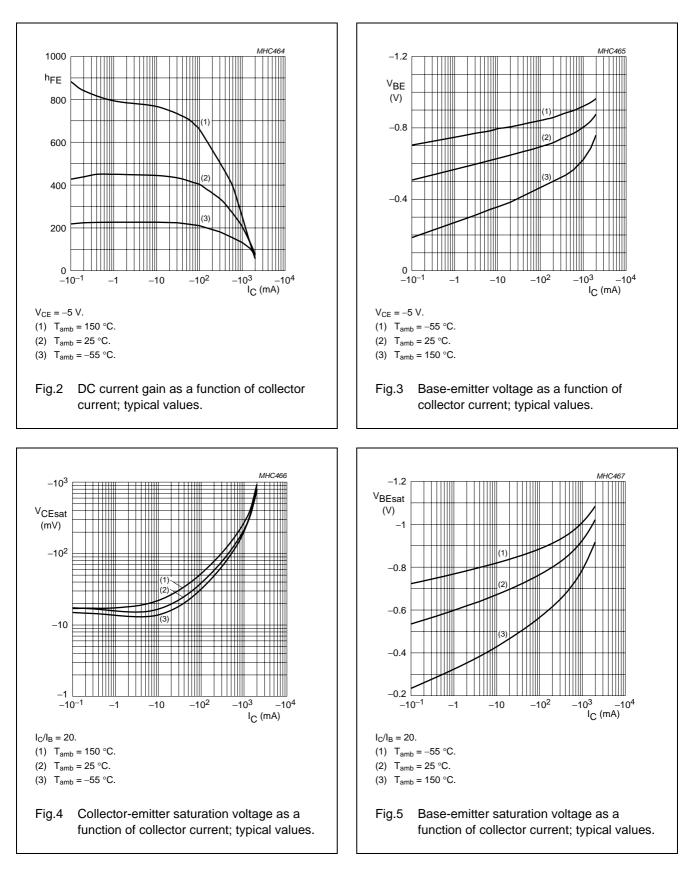
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -40 \text{ V}; \text{ I}_{E} = 0$	-	-	-100	nA
		$V_{CB} = -40 \text{ V}; \text{ I}_{E} = 0; \text{ T}_{amb} = 150 ^{\circ}\text{C}$	-	_	-50	μA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0$	-	_	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ mA}$	300	_	_	
		$V_{CE} = -5 \text{ V}; I_{C} = -100 \text{ mA}$	300	_	800	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$	250	_	_	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ A}$	160	-	_	
		$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ A}; \text{ note } 1$	50	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -1 \text{ mA}$	_	-80	-120	mV
		$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}$	-	-100	-145	mV
		$I_{C} = -1 \text{ A}; I_{B} = -100 \text{ mA}; \text{ note } 1$	_	-180	-250	mV
		$I_{\rm C} = -2$ A; $I_{\rm B} = -200$ mA	-	-370	-530	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -1 \text{ A}; I_{B} = -100 \text{ mA}; \text{ note } 1$	_	180	<250	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = -1$ A; $I_{\rm B} = -100$ mA	_	_	-1.1	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ A}$	-	-	-1	V
f _T	transition frequency	$I_{C} = -50 \text{ mA}; V_{CE} = -10 \text{ V};$ f = 100 MHz	150	-	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	-	_	12	pF

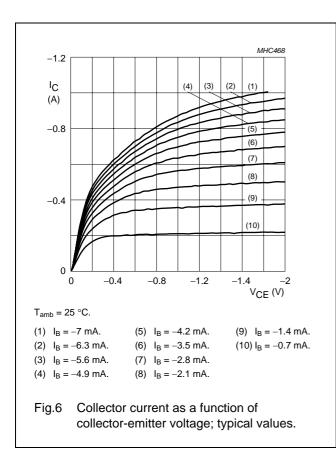
Note

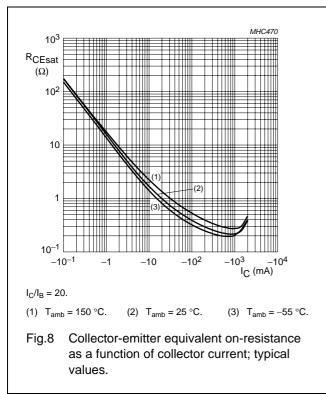
1. Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

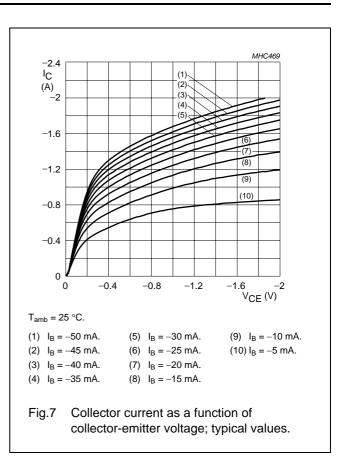
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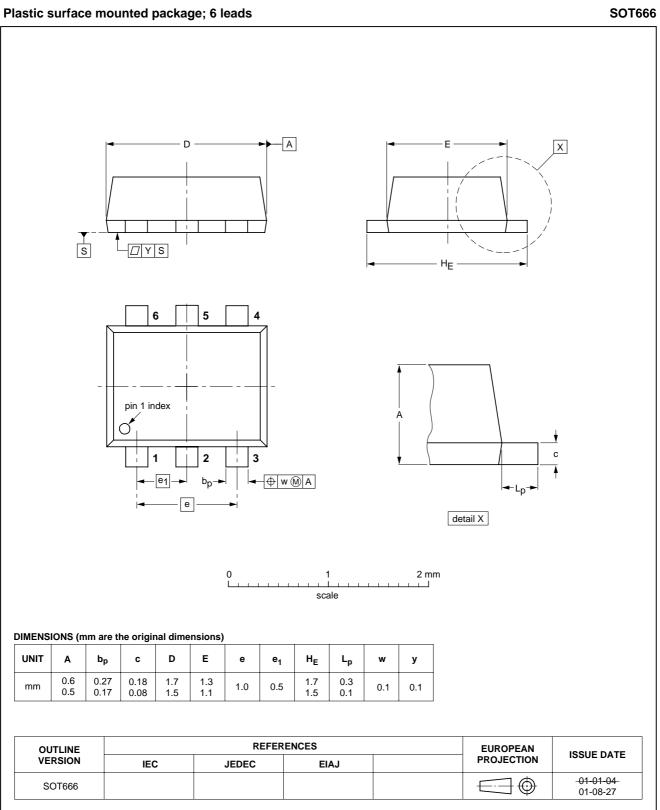
PBSS5240V







PACKAGE OUTLINE



PBSS5240V

40 V low V_{CEsat} PNP transistor

PBSS5240V

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

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Contact information

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